

SEMICONDUCTOR*

November 2013

FQPF20N06L — N-Channel QFET[®] MOSFET

FQPF20N06L

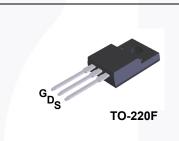
N-Channel QFET[®] MOSFET **60 V, 15.7 A, 55 m**Ω

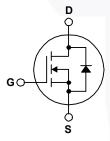
Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

Features

- 15.7 A, 60 V, $R_{DS(on)}$ = 55 m Ω (Max.) @ V_{GS} = 10 V, I_D = 7.85 A
- Low Gate Charge (Typ. 9.5 nC)
- Low Crss (Typ. 35 pF)
- 100% Avalanche Tested
- 175°C Maximum Junction Temperature Rating





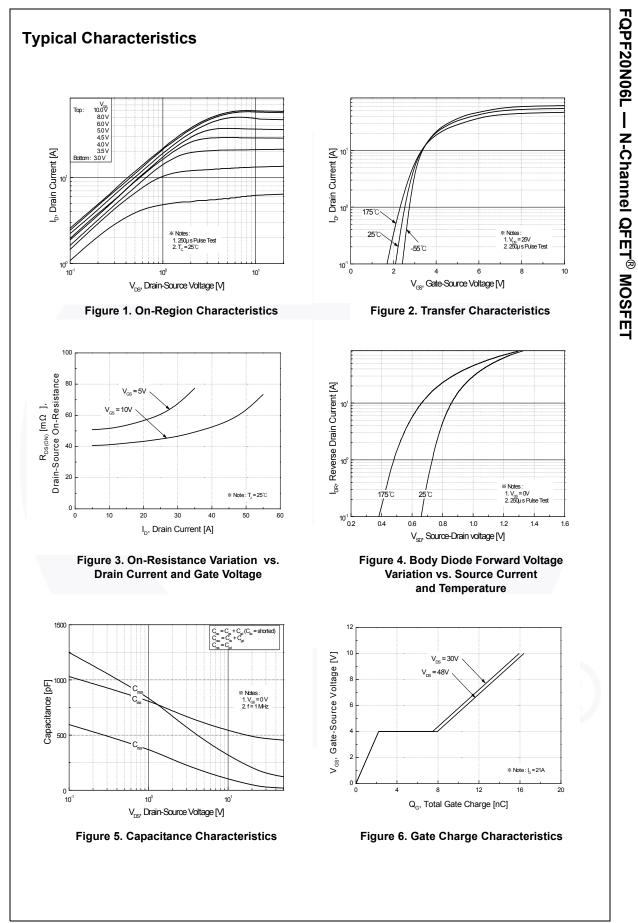
Absolute Maximum Ratings T_C = 25°C unless otherwise noted.

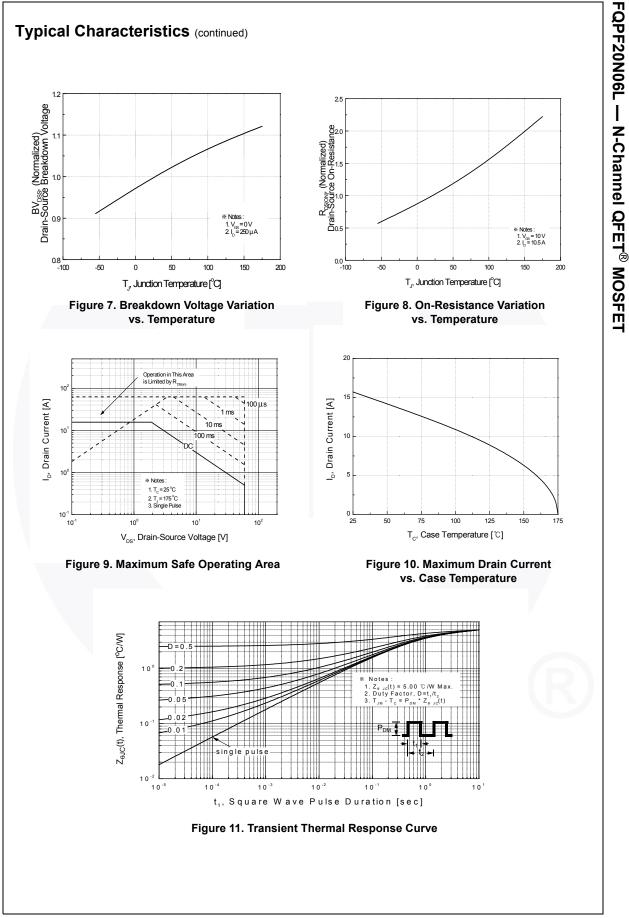
Symbol	Parameter	FQPF20N06L	Unit	
V _{DSS}	Drain-Source Voltage		60	V
I _D	Drain Current - Continuous ($T_C = 25^\circ$	C)	15.7	A
	- Continuous (T _C = 100	°C)	11.1	A
I _{DM}	Drain Current - Pulsed	(Note 1)	62.8	A
V _{GSS}	Gate-Source Voltage		± 20	V
E _{AS}	Single Pulsed Avalanche Energy	(Note 2)	170	mJ
I _{AR}	Avalanche Current	(Note 1)	15.7	A
E _{AR}	Repetitive Avalanche Energy	(Note 1)	3.0	mJ
dv/dt	Peak Diode Recovery dv/dt	(Note 3)	7.0	V/ns
PD	Power Dissipation $(T_C = 25^{\circ}C)$		30	W
	- Derate above 25°C		0.2	W/°C
T _J , T _{STG}	Operating and Storage Temperature Ran	ge	-55 to +175	°C
Τ _L	Maximum Lead Temperature for Solderin 1/8" from Case for 5 seconds	g,	300	°C

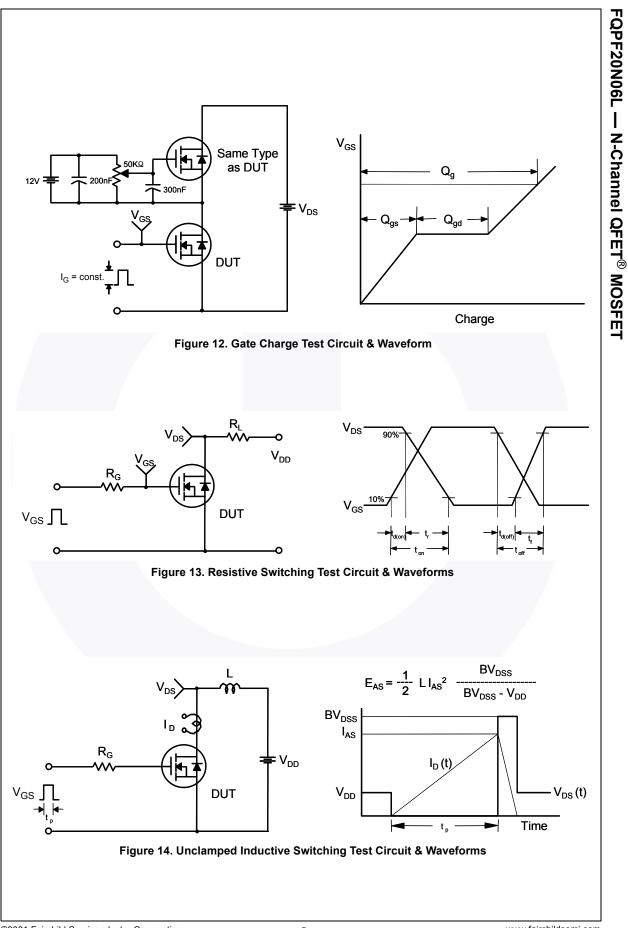
Thermal Characteristics

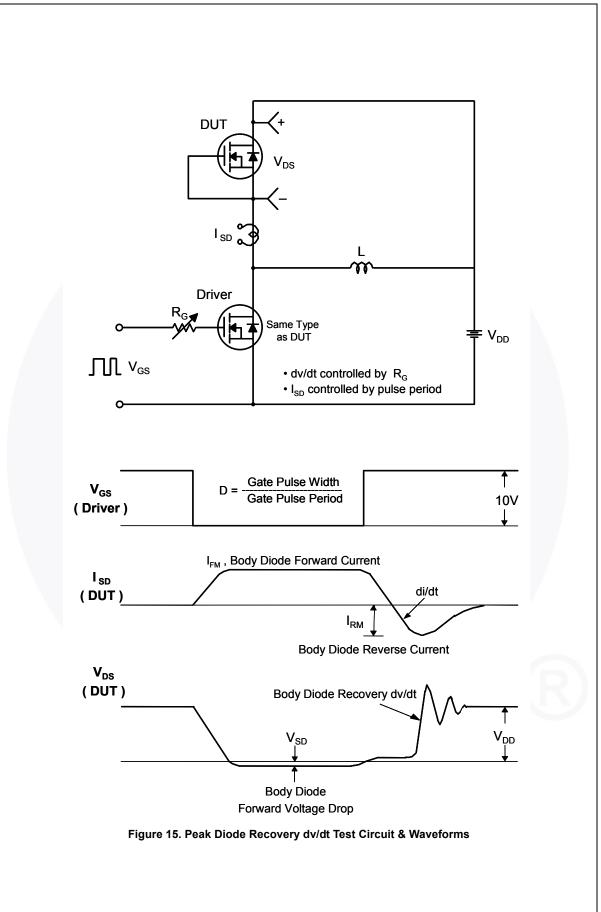
Symbol	Parameter	FQPF20N06L	Unit	
$R_{\theta JC}$	Thermal Resistance, Junction-to-Case, Max.	5.00	°C/W	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	°C/W	

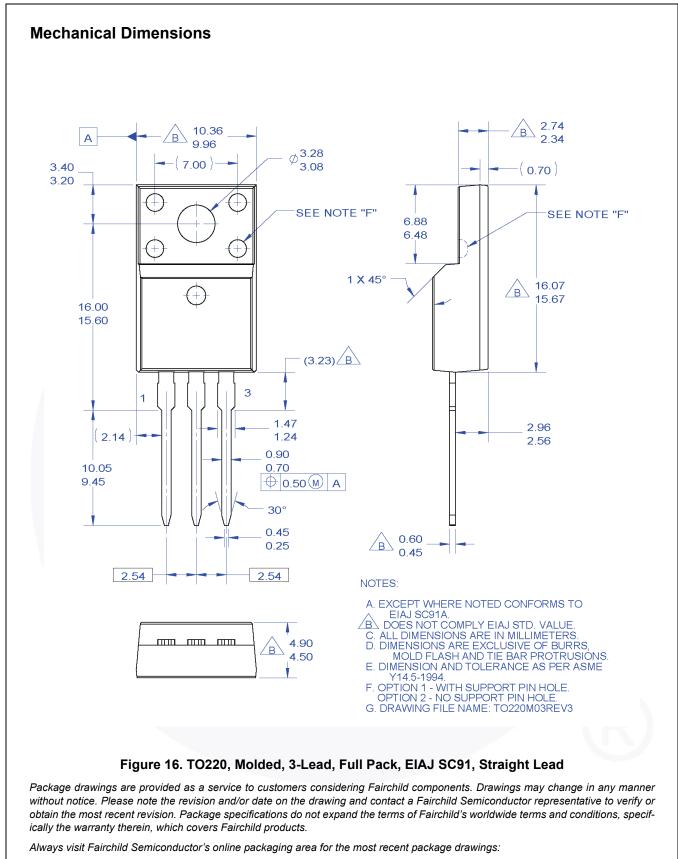
Part Nu	Part NumberTop MarkPackageQPF20N06LFQPF20N06LTO-220F		•		ze Tape Width N/A		th C	Quantity 50 units	
FQPF20							Ę		
lectri	cal Cl	naracteristics	T _C = 25°C	unless otherwise noted.					
Symbol		Parameter		Test Condit	ions	Min	Тур	Max	Unit
Off Cha	1			$y_{1} = 0 y_{1} = 0 z_{0}$. A				
BV _{DSS}		Source Breakdown V	-	V _{GS} = 0 V, I _D = 250 μA		60			V
BV _{DSS} ΔT _J		Breakdown Voltage Temperature Coefficient		I_D = 250 µA, Referenced to 25°C			0.06		V/°C
oss	Zero G	Zero Gate Voltage Drain Current		V_{DS} = 60 V, V_{GS} = 0				1	μA
	Zero Gale Voltage Drain Current		V _{DS} = 48 V, T _C = 150°C			-	10	μA	
GSSF	Gate-E	Body Leakage Curren	t, Forward	V_{GS} = 20 V, V_{DS} = 0				100	nA
GSSR	Gate-E	Body Leakage Curren	it, Reverse	$V_{GS} = -20 V, V_{DS} = 0$	V			-100	nA
On Cha	aracter	istics							
GS(th)	Gate T	hreshold Voltage		$V_{DS} = V_{GS}, I_D = 250$	μA	1.0		2.5	V
R _{DS(on)}	Static	Static Drain-Source		V _{GS} = 10 V, I _D = 7.85 A			0.042	0.055	0
<u> </u>	On-Resistance		$V_{GS} = 5 V, I_{D} = 7.85 A$			0.055	0.07	Ω	
FS	Forwa	rd Transconductance		$V_{DS} = 25 \text{ V}, \text{ I}_{D} = 7.85$	δA		9		S
)vnam	ic Cha	racteristics							
iss		Capacitance		V = 25 V V = 0	M		480	630	pF
'0SS	-	Capacitance		V _{DS} = 25 V, V _{GS} = 0 V, f = 1.0 MHz			175	230	pF
rss		se Transfer Capacitar	nce				35	45	pF
Switch	ing Ch	aracteristics							
l(on)	Turn-C	n Delay Time		V _{DD} = 30 V, I _D = 10.9	5 A		10	30	ns
	Turn-C	In Rise Time		$R_G = 25 \Omega$	<i>,</i>		165	340	ns
l(off)	Turn-C	off Delay Time					35	80	ns
	Turn-C	off Fall Time		(Note 4)			70	150	ns
) ^g	Total G	Bate Charge		V _{DS} = 48 V, I _D = 21 A, V _{GS} = 5 V			9.5	13	nC
) _{gs}	Gate-S	Source Charge					2.5		nC
) _{gd}	Gate-	Drain Charge			(Note 4)		5.5		nC
)rain-9	ourco	Diode Characte	vistics an	d Maximum Rati	inge				
		um Continuous Drair						15.7	Α
SM	Maxim	Maximum Pulsed Drain-Source Diode Forward Current				62.8	Α		
SD	Drain-	Source Diode Forwar	d Voltage	V _{GS} = 0 V, I _S = 15.7 A				1.5	V
r	Revers	se Recovery Time	-	V _{GS} = 0 V, I _S = 21 A,			54		ns
ر الالا	Revers	se Recovery Charge		dI _F / dt = 100 A/µs			75		nC
tes:	Reven	se necovery onarge					10		110











http://www.fairchildsemi.com/package/packageDetails.html?id=PN_TF220-003

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